

DUAL INVERTER BUFFER/DRIVER WITH OPEN-DRAIN OUTPUTS

FEATURES

- Qualified for Automotive Applications
- Supports 5-V V_{CC} Operation
- Max t_{pd} of 3.4 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2 V at V_{CC} = 3.3 V, T_A = 25°C
- Inputs and Open-Drain Outputs Accept Voltages up to 5.5 V
- Ioff Supports Partial-Power-Down Mode
 Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

DESCRIPTION/ORDERING INFORMATION

This dual inverter buffer/driver is designed for 1.65-V to 5.5-V V_{CC} operation.

The output of the SN74LVC2G06-Q1 device is open drain and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32 mA.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
–40°C to 125°C	SOT (SOT-23) – DBV	Tape and reel	SN74LVC2G06QDBVRQ1	C06_
-40 C to 125 C	SOT (SC-70) – DCK	Tape and reel	SN74LVC2G06QDCKRQ1	CT_

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) DBV/DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

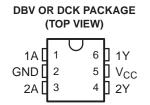
FUNCTION TABLE (EACH INVERTER)

INPUT A	OUTPUT Y
Н	L
L	н



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

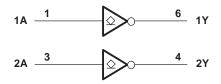
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



Copyright © 2004–2008, Texas Instruments Incorporated



LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽²⁾	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high-impedation	ance or power-off state ⁽²⁾	-0.5	6.5	V
Vo	Voltage range applied to any output in the high or low	state ⁽²⁾⁽³⁾	-0.5	6.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
lo	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA
0	Package thermal impedance ⁽⁴⁾	DBV package		165	°C/W
θ_{JA}		DCK package		259	-0/00
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

2

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V	Supply voltage	Operating	1.65	5.5	V
VCC	Supply voltage	Data retention only	1.5		v
		V _{CC} = 1.65 V to 1.95 V	$ \begin{array}{c c} 1.65 \\ 1.5 \\ 0.65 \times V_{CC} \\ 1.7 \\ 2 \\ 0.7 \times V_{CC} \end{array} $		
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V
VIH	High-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	2		V
		$V_{CC} = 4.5 \text{ V}$ to 5.5 V			
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V _{IL}		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
	Low-level input voltage $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$			0.8	v
	I_1 Input voltage V_0 Output voltage D_L Low-level output current D_L Input transition rise or fall rate	$V_{CC} = 4.5 V \text{ to } 5.5 V$		$0.3\times V_{CC}$	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	5.5	V
		V _{CC} = 1.65 V		4	
		V _{CC} = 2.3 V		8	
I _{OL}	Low-level output current	N 2 N		16	mA
	Input voltage Output voltage	$V_{CC} = 3 V$		24	
		V _{CC} = 4.5 V		32	
		V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
		$V_{CC} = 5 V \pm 0.5 V$		5	l.
T _A	Operating free-air temperature	· · · · · · · · · · · · · · · · · · ·	-40	125	°C

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST C	CONDITIONS	V _{cc}	MIN TYP ⁽¹⁾ MAX	UNIT
	I _{OL} = 100 μA		1.65 V to 5.5 V	0.1	
PARAMETER V _{OL} I _I A inputs I _{off} I _{CC} ΔI _{CC} C _i	I _{OL} = 4 mA		1.65 V	0.45	
	I _{OL} = 8 mA		2.3 V	0.3	
V _{OL} I ₁ A inputs I _{off} I _{CC} ΔI _{CC}	1 10 10	$T_A = -40^{\circ}C$ to $85^{\circ}C$	2.1/	0.4	
	I _{OL} = 16 mA	T _A = 125°C	3 V	0.45	V
	1 04	$T_A = -40^{\circ}C$ to $85^{\circ}C$	2.1/	0.55	
	I _{OL} = 24 mA	T _A = 125°C	3 V	0.65	
	1 20 m 1	$T_A = -40^{\circ}C$ to $85^{\circ}C$	45.1	0.55	
	I _{OL} = 32 mA	T _A = 125°C	4.5 V	0.65	
I _I A inputs	$V_{I} = 5.5 V \text{ or GND}$		0 to 5.5 V	±5	μΑ
l _{off}	$V_{I} \text{ or } V_{O} = 5.5 \text{ V}$		0	±10	μΑ
I _{CC}	$V_{I} = 5.5 V \text{ or GND},$	I _O = 0	1.65 V to 5.5 V	10	μΑ
ΔI _{CC}	One input at V _{CC} – 0.6 V,	Other inputs at V_{CC} or GND	3 V to 5.5 V	500	μA
C _i	$V_I = V_{CC}$ or GND		3.3 V	3.5	pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

3



SCES617A-OCTOBER 2004-REVISED APRIL 2008

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
	(INFOT)	(001-01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	А	Y	1.8	7.2	1	3.9	1	3.4	1	2.9	ns

Operating Characteristics

 $T_A = 25^{\circ}C$

PARAMETERTEST CONDITIONS $V_{CC} = 1.8 \text{ V}$ $V_{CC} = 2.5 \text{ V}$ TYPTYP		$V_{CC} = 3.3 V$	$V_{CC} = 5 V$	UNIT				
			TYP	TYP	TYP	TYP	UNIT	
C_{pd}	Power dissipation capacitance	f = 10 MHz	2	2	3	4	pF	

4

Copyright © 2004–2008, Texas Instruments Incorporated

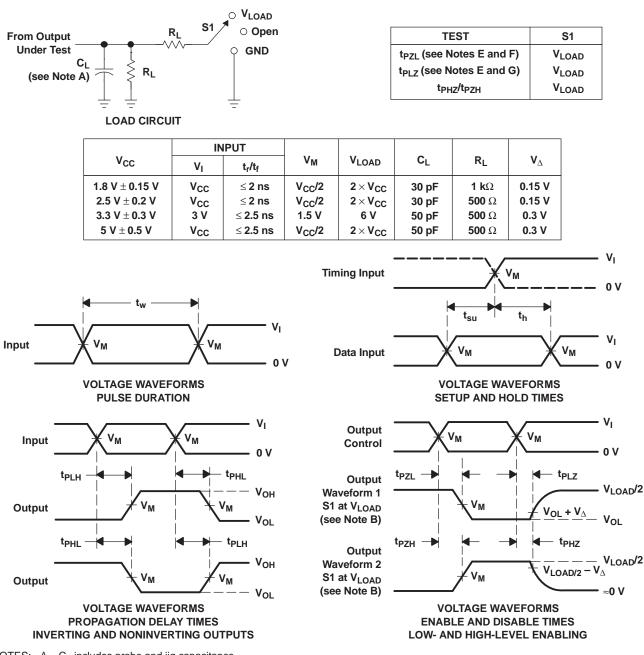
SN74LVC2G06-Q1



www.ti.com

SCES617A-OCTOBER 2004-REVISED APRIL 2008

PARAMETER MEASUREMENT INFORMATION (OPEN DRAIN)



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. Since this device has open-drain outputs, t_{PLZ} and t_{PZL} are the same as t_{pd}
- F. t_{PZL} is measured at V_M.
- G. t_{PLZ} is measured at $V_{OL} + V_{\Delta}$.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LVC2G06QDCKRQ1	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	СТО	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LVC2G06-Q1 :



PACKAGE OPTION ADDENDUM

6-Feb-2020

Catalog: SN74LVC2G06

• Enhanced Product: SN74LVC2G06-EP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	•	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2G06QDCKRQ1	SC70	DCK	6	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

3-Aug-2017



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2G06QDCKRQ1	SC70	DCK	6	3000	203.0	203.0	35.0

DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AB.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2020, Texas Instruments Incorporated